Integrated SIM card passive filter array with ESD protection to IEC61000-4-2, level 4

Rev. 01 — 12 November 2007

Product data sheet

1. Product profile

1.1 General description

The IP4064CX8/LF and IP4364CX8/LF are 3-channel RC low-pass filter arrays which are designed to provide filtering of undesired RF signals in the 800 MHz to 3000 MHz frequency band. In addition, the IP4064CX8/LF and IP4364CX8/LF incorporate diodes to provide protection to downstream components against Electrostatic Discharge (ESD) voltages as high as ± 15 kV contact and > ± 15 kV air discharge, far exceeding IEC61000-4-2, level 4. The IP4064CX8/LF and IP4364CX8/LF are fabricated using monolithic silicon technology and integrate three resistors and seven high-level ESD-protection diodes in a single wafer level chip-scale package. These features make the IP4064CX8/LF and IP4364CX8/LF ideal for use in applications requiring component miniaturization, such as mobile phone handsets, cordless telephones and personal digital devices.

1.2 Features

- Pb-free and RoHS compliant
- 3-channel SIM card interface integrated RC-filter array
- 100 Ω/100 Ω/47 Ω series channel resistors integrated
- Downstream ESD protection up to ±15 kV (contact) exceeding IEC61000-4-2, level 4
- Wafer level chip-scale package with 0.4 mm (IP4364CX8/LF) and 0.5 mm (IP4064CX8/LF) pitch

1.3 Applications

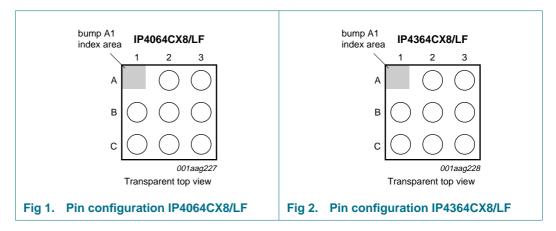
SIM interfaces in e.g. cellular and PCS mobile handsets



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2. Pinning information

2.1 Pinning



2.2 Pin description

Table 1.	Pin description
Pin	Description
A2	external pin 1
A3	internal pin 1
B1	external pin 2
B2	ground
B3	internal pin 2
C1	external pin 3
C2	supply ESD protection
C3	internal pin 3

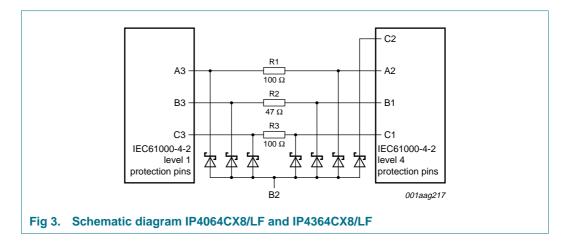
3. Ordering information

Table 2.Ordering information

Type number	Package				
	Name	Description	Version		
IP4064CX8/LF	WLCSP8	wafer level chip-size package; 8 bumps; 1.41 \times 1.41 \times 0.7 mm	IP4064CX8/LF		
IP4364CX8/LF	WLCSP8	wafer level chip-size package; 8 bumps; 1.16 \times 1.16 \times 0.66 mm	IP4364CX8/LF		

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4. Functional diagram



5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage		-0.5	+5.5	V
V _{ESD}	electrostatic discharge	pins A2, B1, C1, C2 to B2			
		contact discharge	<u>[1]</u> –15	+15	kV
		air discharge	<u>[1]</u> –15	+15	kV
		IEC 61000-4-2, Level 4, pins A2, B1, C1, C2 to B2			
		contact discharge	-8	+8	kV
		air discharge	-15	+15	kV
		IEC 61000-4-2, Level 1, all other pins to B2			
		contact discharge and air discharge	-2	+2	kV
P _{ch}	channel power dissipation	continuous power; T _{amb} = 70 °C	-	60	mW
P _{tot}	total power dissipation	T _{amb} = 70 °C	-	180	mW
T _{stg}	storage temperature		-55	+150	°C
T _{reflow(peak)}	peak reflow temperature	10 s maximum	-	260	°C
T _{amb}	ambient temperature		-30	+85	°C

[1] Device is tested with 1000 pulses of ±15 kV contact discharges each, according the IEC61000-4-2 model and so exceeds the specified level 4 (8 kV contact discharge) by far.

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6. Characteristics

Table 4.Characteristics $T_{amb} = 25 ^{\circ}C$ unless otherwise specified.						
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{s(ch)} channel series resistance	R1, R3	75	100	125	Ω	
	R2	35.2	47	58.8	Ω	
C _{ch}	channel capacitance	including diode capacitance; V _I = 0 V; f = 1 MHz	-	-	20	pF
V _{BR} I	breakdown voltage	I _{test} = 1 mA	6	-	10	V
I _{LR} I	reverse leakage current	V _I = 3 V	-	-	50	nA

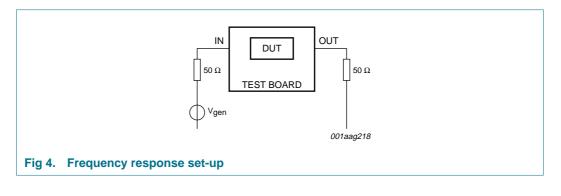
IP4064CX8LF_IP4364CX8LF_1

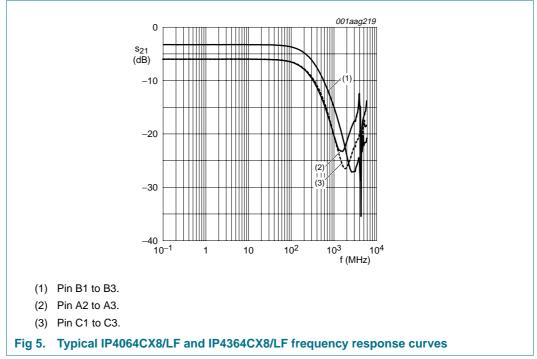
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7. Application information

7.1 Insertion loss

The IP4064CX8/LF and IP4364CX8/LF is mainly designed as an EMI/RFI filter for SIM card interfaces. The insertion loss in a 50 Ω system for all three channels of the IP4364CX8/LF is shown in Figure 5 as an example. The insertion loss of IP4064CX8/LF is identical. The insertion loss of the three channels was measured with a test PCB utilizing laser drilled micro-via holes that connect the PCB ground plane to the ground pins.

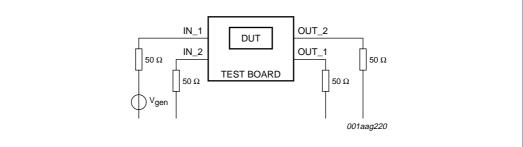




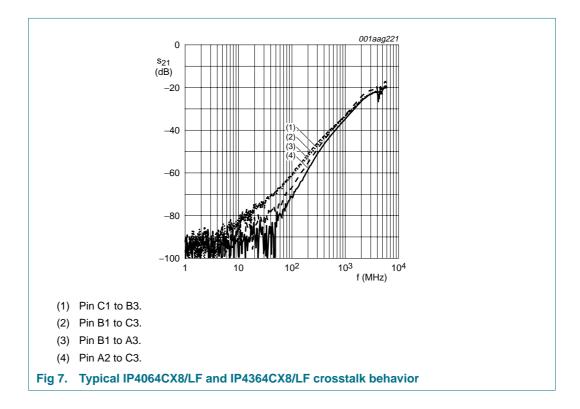
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7.2 Crosstalk

The set-up for crosstalk measurements in a 50 Ω system from one channel to another is shown in Figure 6. Four typical examples of crosstalk measurement results are depicted in Figure 7. Channels not shown there behave similar. Unused channels are terminated with 50 Ω to ground.







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8. Package outline

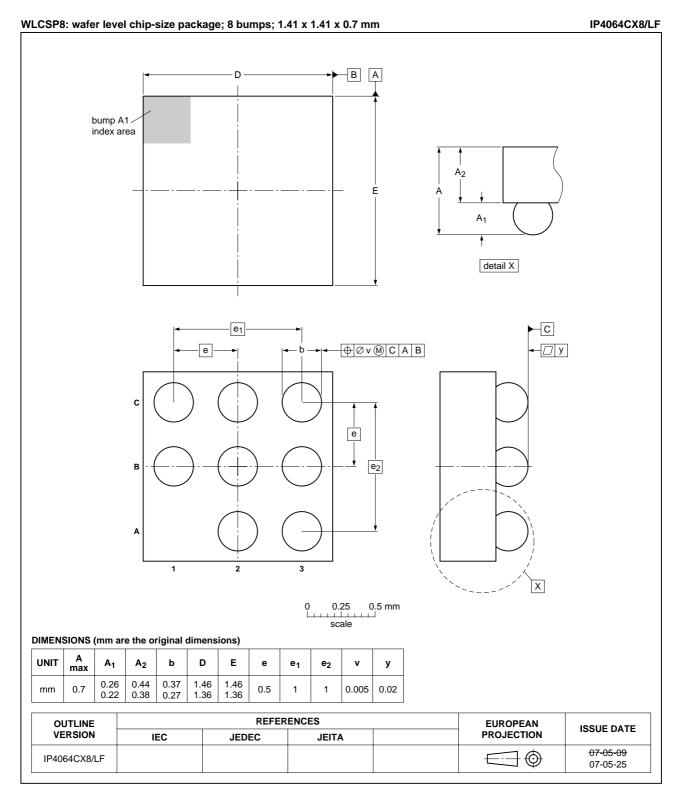


Fig 8. Package outline IP4064CX8/LF (WLCSP8)

IP4064CX8LF_IP4364CX8LF_1

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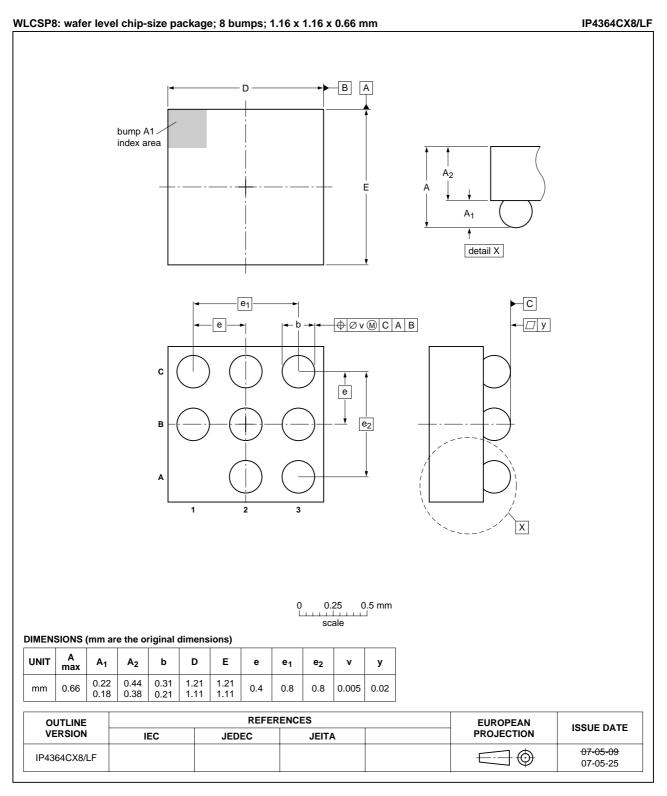


Fig 9. Package outline IP4364CX8/LF (WLCSP8)

IP4064CX8LF_IP4364CX8LF_1

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9. Soldering

9.1 Introduction to soldering WLCSP packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering WLCSP (Wafer Level Chip-Size Packages) can be found in application note *AN10439 "Wafer Level Chip Scale Package"* and in application note *AN10365 "Surface mount reflow soldering description"*.

Wave soldering is not suitable for this package.

All NXP WLCSP packages are lead-free.

9.2 Board mounting

Board mounting of a WLCSP requires several steps:

- 1. Solder paste printing on the PCB
- 2. Component placement with a pick and place machine
- 3. The reflow soldering itself

9.3 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 10</u>) than a PbSn process, thus reducing the process window
- Solder paste printing issues, such as smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature), and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic) while being low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 5

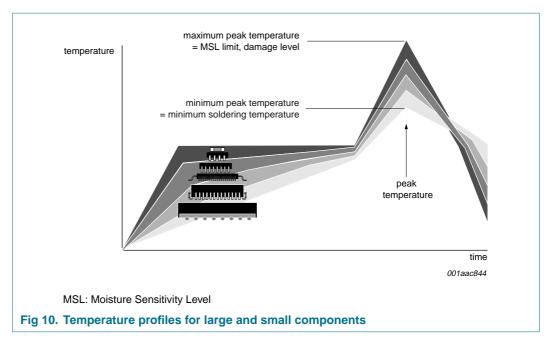
Package thickness (mm)	Package reflow temperature (°C) Volume (mm ³)			
	< 350	350 to 2000	> 2000	
< 1.6	260	260	260	
1.6 to 2.5	260	250	245	
> 2.5	250	245	245	

Table 5. Lead-free process (from J-STD-020C)

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 10.

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For further information on temperature profiles, refer to application note AN10365 "Surface mount reflow soldering description".

9.3.1 Stand off

The stand off between the substrate and the chip is determined by:

- The amount of printed solder on the substrate
- The size of the solder land on the substrate
- The bump height on the chip

The higher the stand off, the better the stresses are released due to TEC (Thermal Expansion Coefficient) differences between substrate and chip.

9.3.2 Quality of solder joint

A flip-chip joint is considered to be a good joint when the entire solder land has been wetted by the solder from the bump. The surface of the joint should be smooth and the shape symmetrical. The soldered joints on a chip should be uniform. Voids in the bumps after reflow can occur during the reflow process in bumps with high ratio of bump diameter to bump height, i.e. low bumps with large diameter. No failures have been found to be related to these voids. Solder joint inspection after reflow can be done with X-ray to monitor defects such as bridging, open circuits and voids.

9.3.3 Rework

In general, rework is not recommended. By rework we mean the process of removing the chip from the substrate and replacing it with a new chip. If a chip is removed from the substrate, most solder balls of the chip will be damaged. In that case it is recommended not to re-use the chip again.

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Device removal can be done when the substrate is heated until it is certain that all solder joints are molten. The chip can then be carefully removed from the substrate without damaging the tracks and solder lands on the substrate. Removing the device must be done using plastic tweezers, because metal tweezers can damage the silicon. The surface of the substrate should be carefully cleaned and all solder and flux residues and/or underfill removed. When a new chip is placed on the substrate, use the flux process instead of solder on the substrate. Place and align the new chip while viewing with a microscope. To reflow the solder, use the solder profile shown in application note *AN10365 "Surface mount reflow soldering description"*.

9.3.4 Cleaning

Cleaning can be done after reflow soldering.

10. Abbreviations

Table 6.	Abbreviations
Acronym	Description
DUT	Device Under Test
EMI	ElectroMagnetic Interference
ESD	ElectroStatic Discharge
PCB	Printed-Circuit Board
PCS	Personal Communication System
RFI	Radio Frequency Interference
RoHS	Restriction Of the use of certain Hazardous Substances directive
SIM	Subscriber Identity Module

11. Revision history

Table 7. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
IP4064CX8LF_IP4364CX8LF	_1 20071112	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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